Rochester Electronics

Datasheet

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

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National Semiconductor

LM107/LM207/LM307 Operational Amplifiers

General Description

The LM107 series are complete, general purpose operational amplifiers, with the necessary frequency compensation built into the chip. Advanced processing techniques make the input currents a factor of ten lower than industry standards like the 709. Yet, they are a direct, plug-in replacement for the 709, LM101A and 741.

The LM107 series offers the features of the LM101A, which makes its application nearly foolproof. In addition, the device provides better accuracy and lower noise in high impedance circuitry. The low input currents also make it particularly well suited for long interval integrators or timers, sample and hold circuits and low frequency waveform generators. Further, replacing circuits where matched transistor pairs buffer the inputs of conventional IC op amps, it can give lower offset voltage and drift at a lower cost.

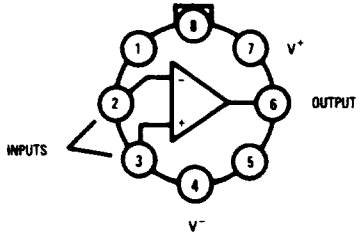
The LM107 is guaranteed over a −55°C to +125°C temperature range, the LM207 from −25°C to +85°C and the LM307 from 0°C to +70°C.

Features

- Offset voltage 3 mV maximum over temperature
- Input current 100 nA maximum over temperature
- Offset current 20 nA maximum over temperature
- Guaranteed drift characteristics

Connection Diagrams

Metal Can Package



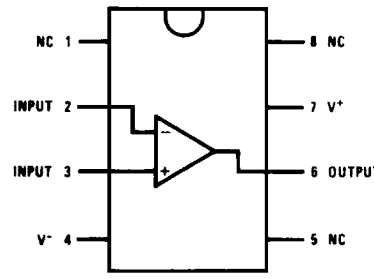
TL/H/7757–2

Note: Pin 4 connected to case.

Top View

Order Number LM107H, LM107H/883,*
LM207H or LM307H
See NS Package Number H08C

Dual-in-Line Package



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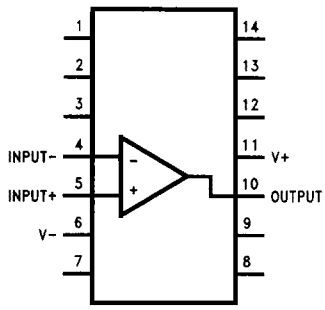
Top View

Order Number LM107J, LM107J/883,*
LM207J or LM307J
See NS Package Number J08A

Order Number LM307N
See NS Package Number N08A

Dual-in-Line Package



TL/H/7757–13

Order Number LM107J-14/883*
See NS Package Number J14A

*Available per SMD# 5962-8958901.

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.
(Note 4)

	LM107/LM207	LM307
Supply Voltage	±22V	±18V
Power Dissipation (Note 1)	500 mW	500 mW
Differential Input Voltage	±30V	±30V
Input Voltage (Note 2)	±15V	±15V
Output Short Circuit Duration	Continuous	Continuous
Operating Temperature Range (T_A)		
(LM107)	−55°C to +125°C	0°C to +70°C
(LM207)	−25°C to +85°C	
Storage Temperature Range	−65°C to +150°C	−65°C to +150°C
Lead Temperature (Soldering, 10 sec)	260°C	260°C

	T_{MIN}	T_{MAX}
LM107	−55°C	+125°C
LM207	−25°C	+85°C
LM307	0°C	+70°C

ESD rating to be determined.

Electrical Characteristics (Note 3)

Parameter	Conditions	LM107/LM207			LM307			Units
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	T_A = 25°C, $R_S \leq 50\ k\Omega$		0.7	2.0		2.0	7.5	mV
Input Offset Current	T_A = 25°C		1.5	10		3.0	50	nA
Input Bias Current	T_A = 25°C		30	75		70	250	nA
Input Resistance	T_A = 25°C	1.5	4.0		0.5	2.0		MΩ
Supply Current	T_A = 25°C V_S = ±20V V_S = ±15V		1.8	3.0		 1.8	 3.0	 mA mA
Large Signal Voltage Gain	T_A = 25°C, V_S = ±15V V_{OUT} = ±10V, $R_L \geq 2\ k\Omega$	50	160		25	160		V/mV
Input Offset Voltage	$R_S \leq 50\ k\Omega$			3.0			10	mV
Average Temperature Coefficient of Input Offset Voltage			3.0	15		6.0	30	μV/°C
Input Offset Current				20			70	nA
Average Temperature Coefficient of Input Offset Current	25°C ≤ $T_A \leq T_{MAX}$ $T_{MIN} \leq T_A \leq$ 25°C		0.01 0.02	0.1 0.2		0.01 0.02	0.3 0.6	nA/°C nA/°C
Input Bias Current				100			300	nA
Supply Current	T_A = +125°C, V_S = ±20V		1.2	2.5				mA

Electrical Characteristics (Note 3) (Continued)

Parameter	Conditions	LM107/LM207			LM307			Units
		Min	Typ	Max	Min	Typ	Max	
Large Signal Voltage Gain	$V_S = \pm 15V$, $V_{OUT} = \pm 10V$ $R_L \geq 2\ k\Omega$	25			15			V/mV
Output Voltage Swing	$V_S = \pm 15V$ $R_L = 10\ k\Omega$ $R_L = 2\ k\Omega$	±12 ±10	±14 ±13		±12 ±10	±14 ±13		V V
Input Voltage Range	$V_S = \pm 20V$ $V_S = \pm 15V$	±15	 +15 −13		 ±12	 +15 −13		V V
Common Mode Rejection Ratio	$R_S \leq 50\ k\Omega$	80	96		70	90		dB
Supply Voltage Rejection Ratio	$R_S \leq 50\ k\Omega$	80	96		70	96		dB

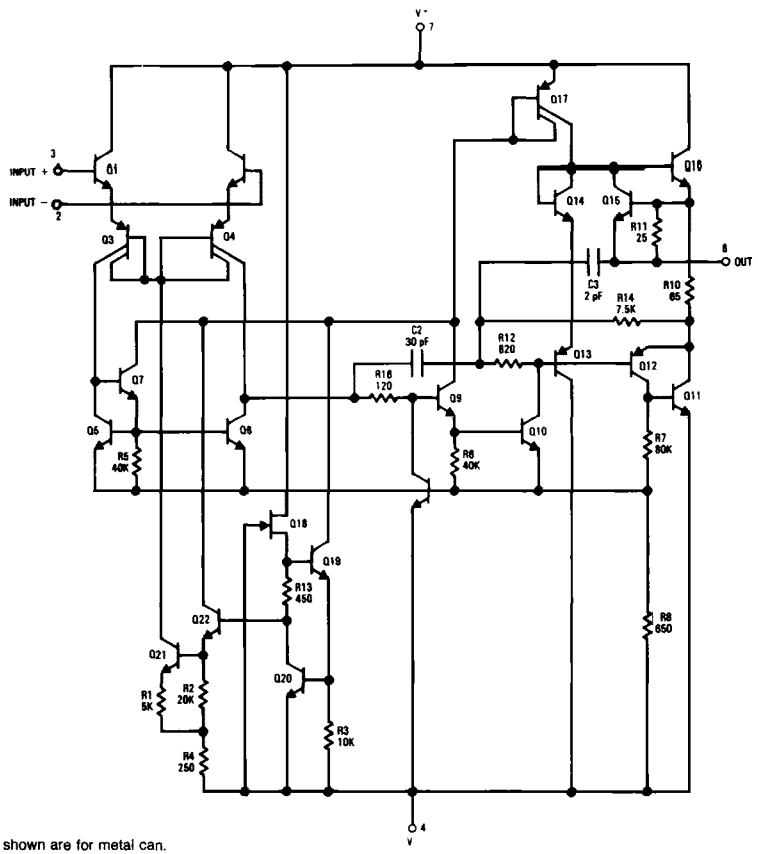
Note 1: The maximum junction temperature of the LM107 is 150°C, and the LM207/LM307 is 100°C. For operating at elevated temperatures, devices in the H08 package must be derated based on a thermal resistance of 165°C/W, junction to ambient, or 30°C/W, junction to case. The thermal resistance of the dual-in-line package is 100°C/W, junction to ambient.

Note 2: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Note 3: These specifications apply for $\pm 5V \leq V_S \leq +20V$ and $-55°C \leq T_A \leq +125°C$ for the LM107 or $-25°C \leq T_A +85°C$ for the LM207, and $0°C \leq T_A \leq +70°C$ and $\pm 5V \leq V_S \leq \pm 15V$ for the LM307 unless otherwise specified.

Note 4: Refer to RETS107X for LM107H and LM107J military specifications.

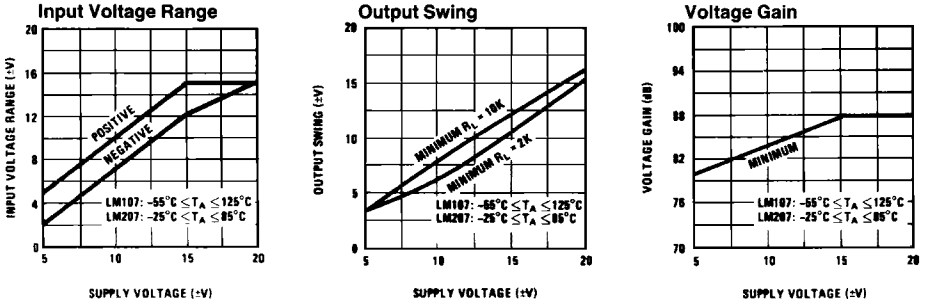
Schematic Diagram*



*Pin connections shown are for metal can.

TL/H/7757–1

Guaranteed Performance Characteristics LM107/LM207



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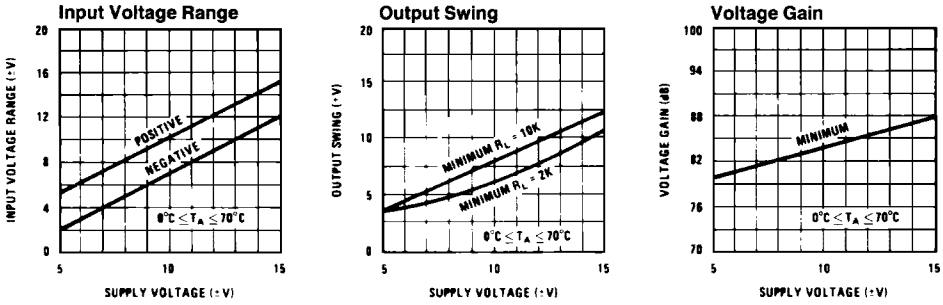
Guaranteed Performance Characteristics LM307



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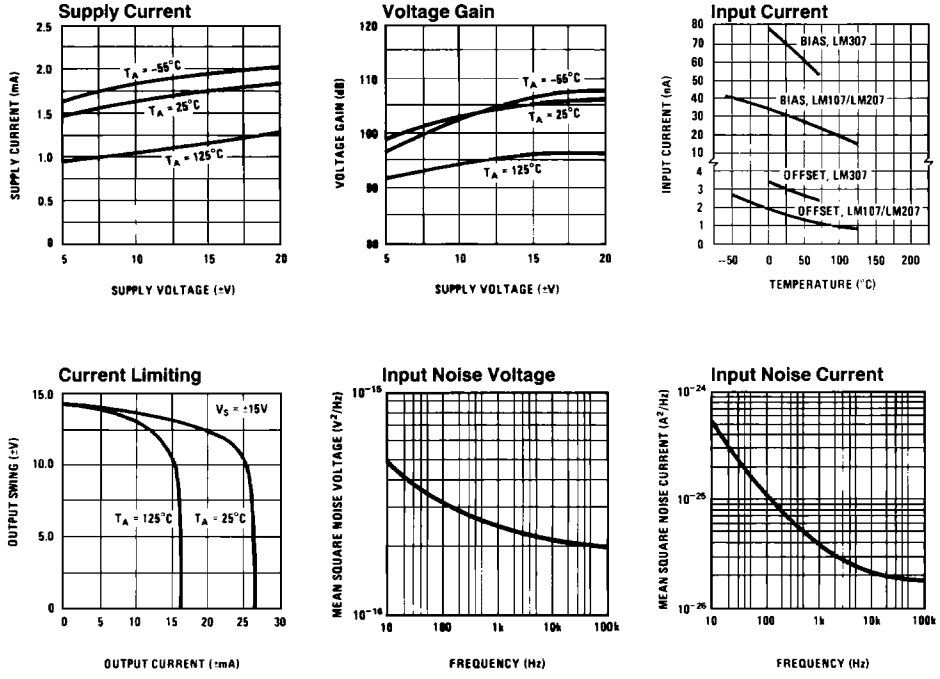
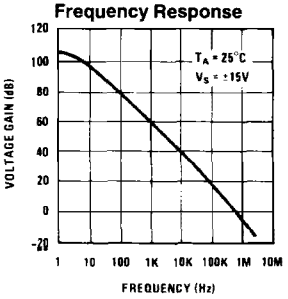
Typical Performance Characteristics



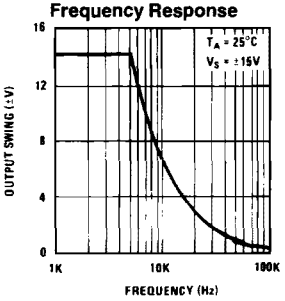
TL/H/7757–6

Typical Performance Characteristics (Continued)

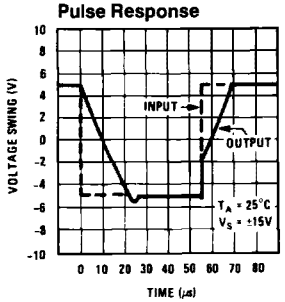
Open Loop Frequency Response



Large Signal Frequency Response



Voltage Follower Pulse Response



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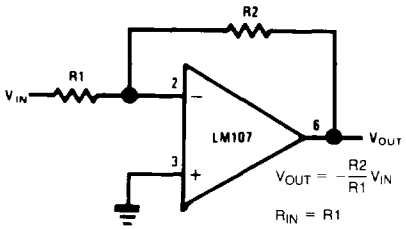
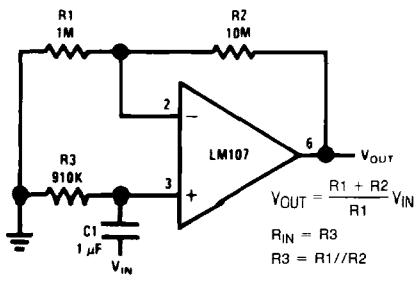
Typical Applications**

Inverting Amplifier



TL/H/7757-8

Non-Inverting AC Amplifier



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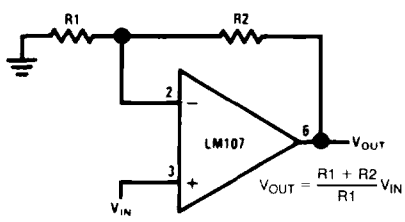
Non-Inverting Amplifier



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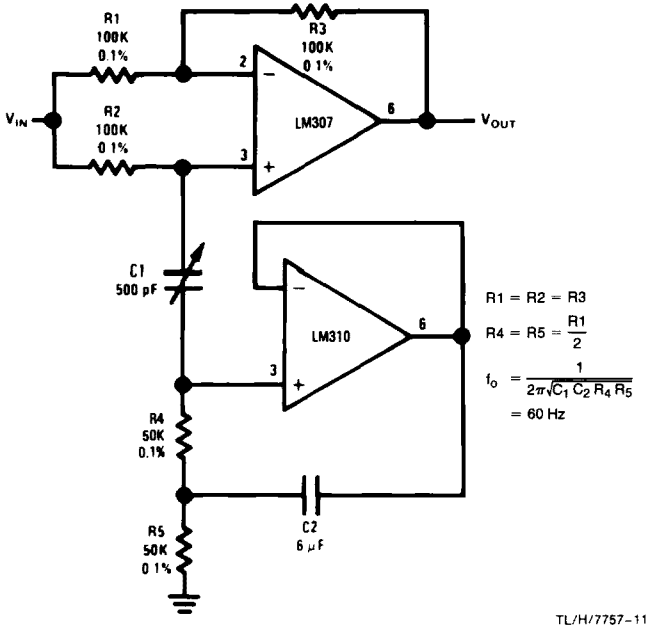
**Pin connections shown are for metal can.

Typical Applications** (Continued)

Turntable Notch Filter



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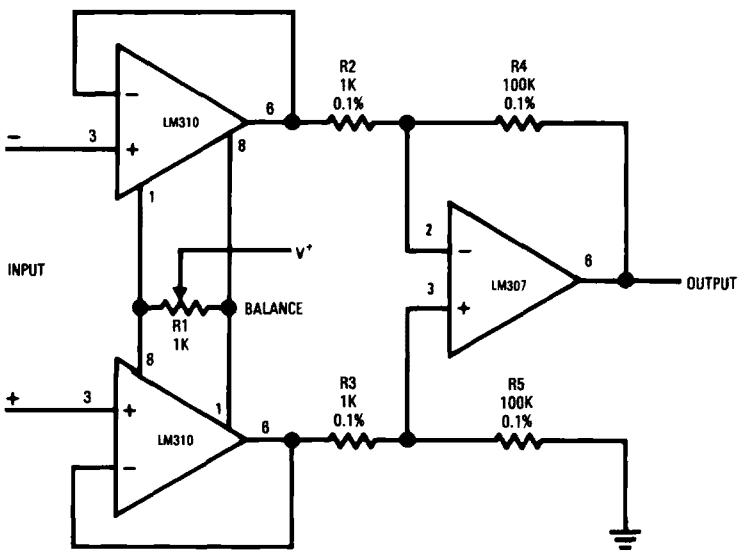
Differential Input Instrumentation Amplifier



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**Pin connections shown are for metal can.